

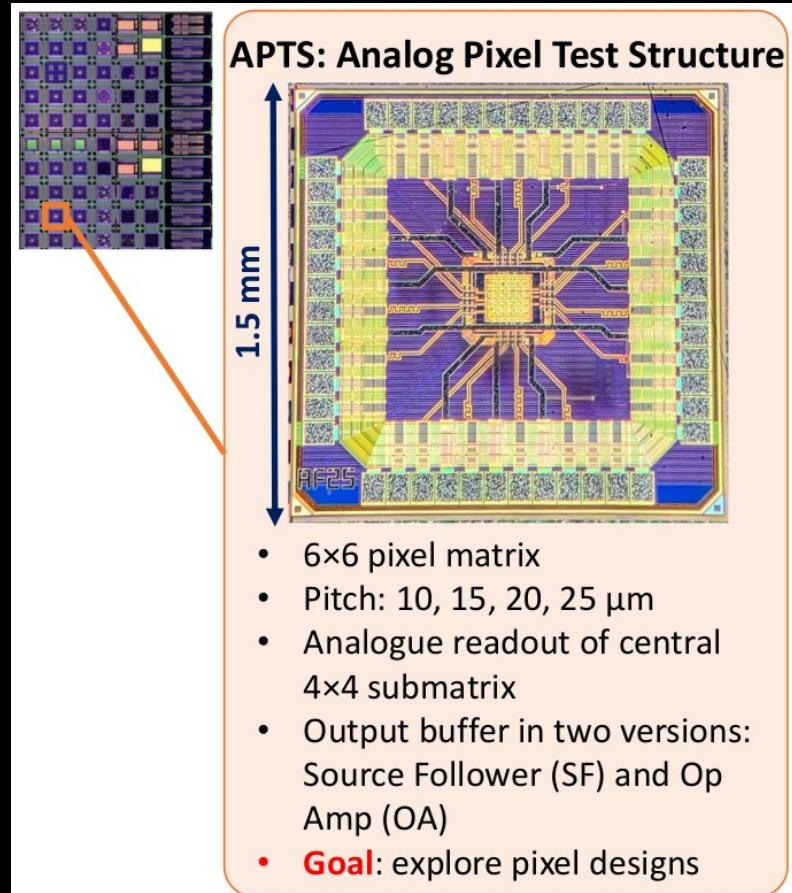
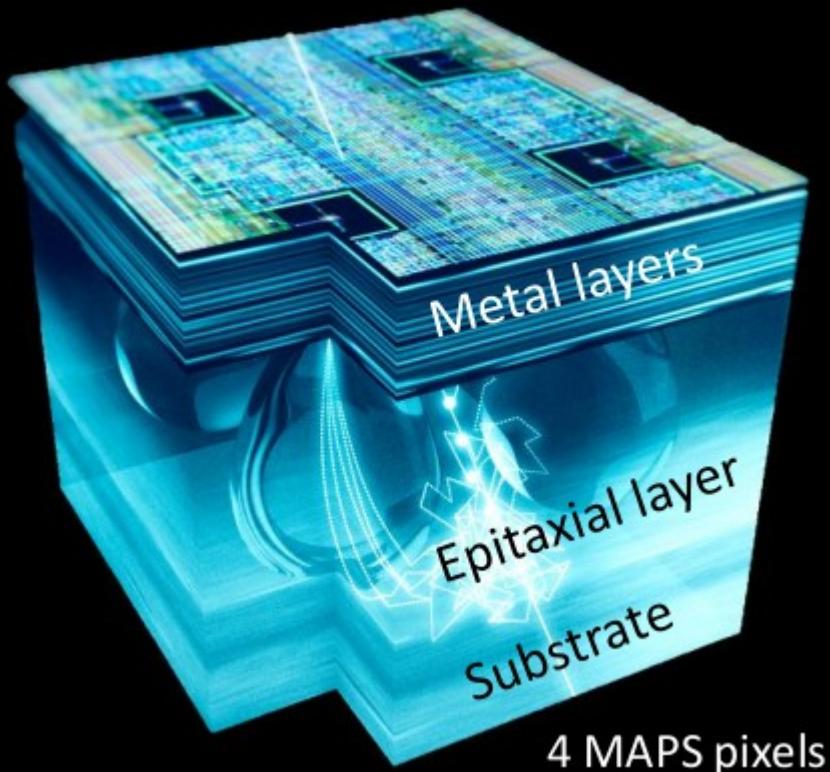
Status & Plan

Bari, 5/11/2024

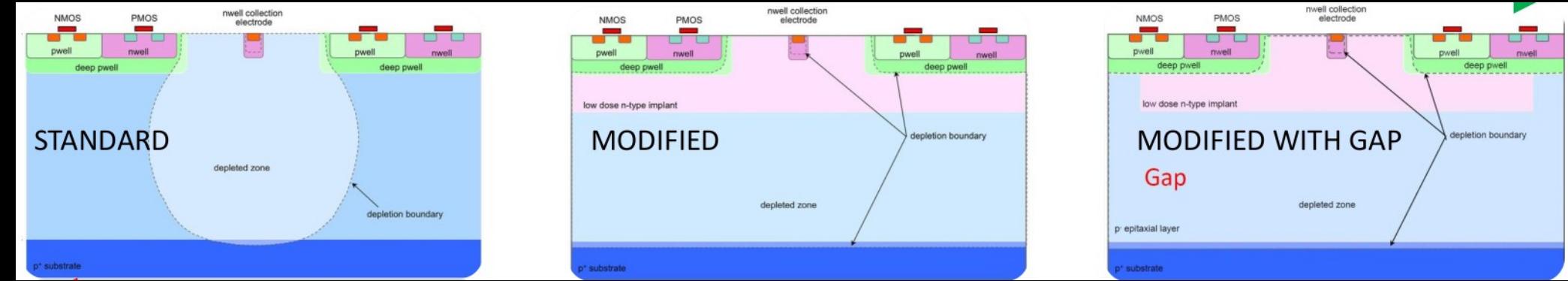
People involved:

Angelo Colelli, Rajendra Nath Patra, Shyam Kumar, Triloki Triloki & Francesco

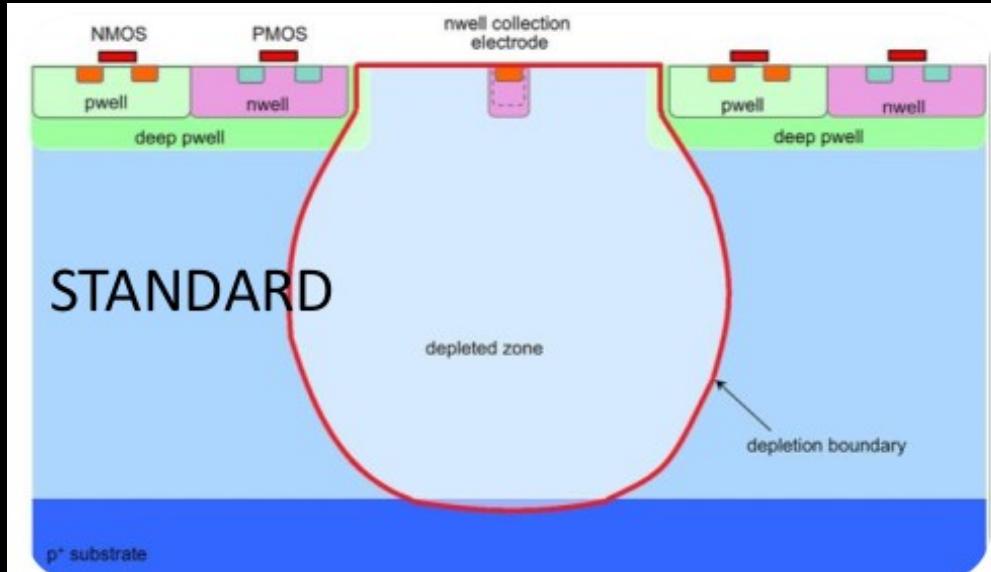
The 65 nm CMOS technology



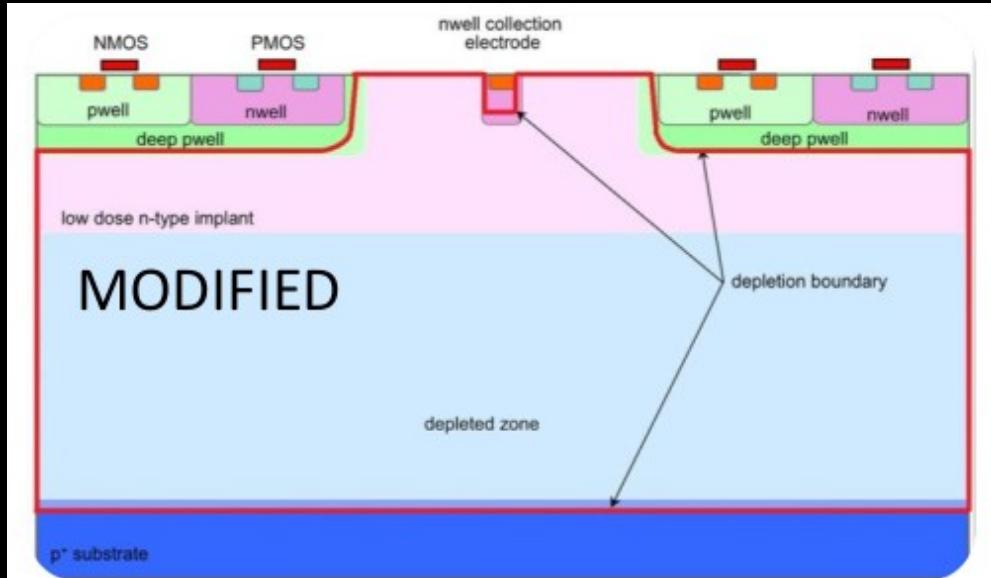
The 65 nm CMOS technology



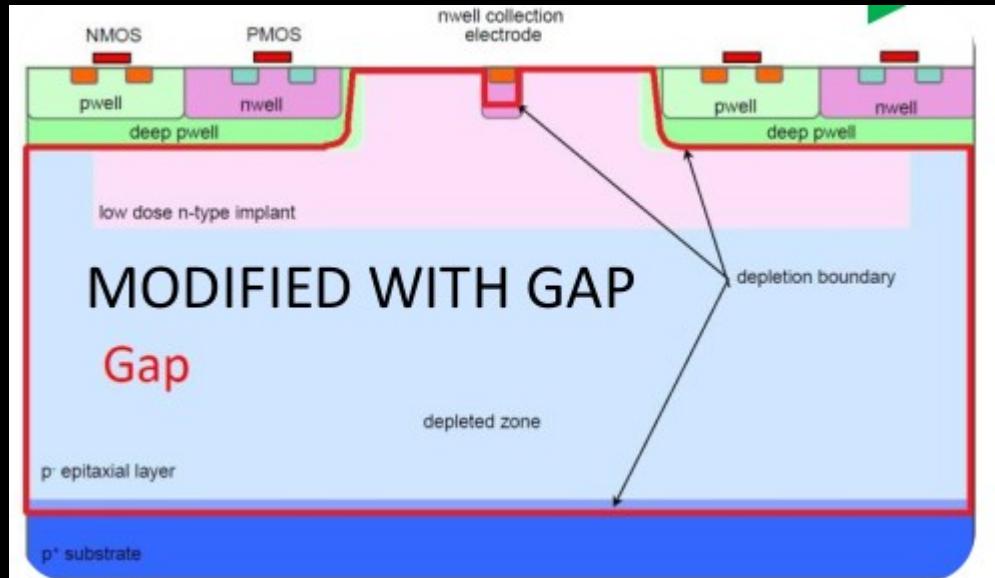
The 65 nm CMOS technology



The 65 nm CMOS technology



The 65 nm CMOS technology



Test Beam @ SPS (Sept-Oct 2024)



Time schedule plan

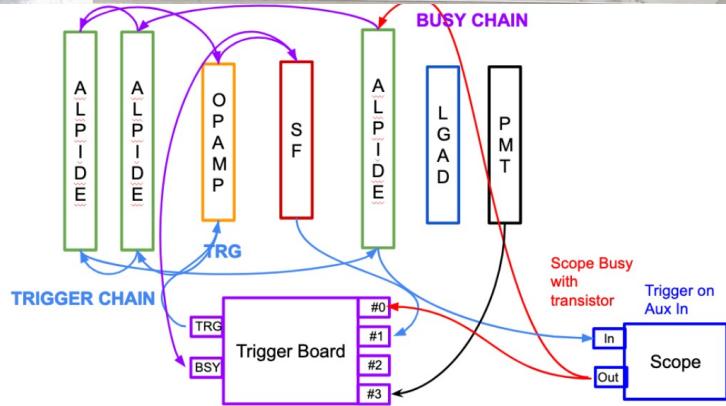
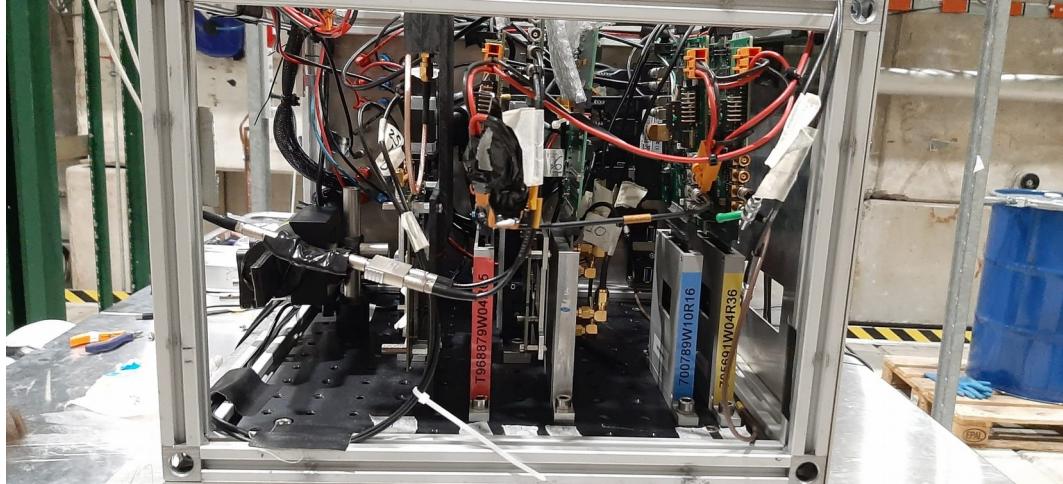


- Monday 23 → traveling to CERN
- From Monday 23 to Wednesday 25 September → mounting the telescope in bld 23 [ADAMS] + dosimeter
- Wednesday 25 September → moving to SPS (through the tunnel [ADAMS])
- Wednesday 25 September → AO10P 1E15 → 6pm alignment and night start data taking
- Thursday 26 September → AO10P 1E15 → data taking
- Friday 27 September → AO10P 1E14 → 9am DUT substitution and alignment and 1pm start data taking
- Saturday 28 September → AO10P 1E13 → 9am DUT substitution and alignment and 1pm start data taking
- Sunday 29 September → AO10AP → 9am DUT substitution and alignment and 1pm start data taking
- Monday 30 September → AO10AP → data taking
- Tuesday 1 October → change DUT (?)
- Wednesday 2 October → leaving SPS
- Thursday 3 October → leaving CERN

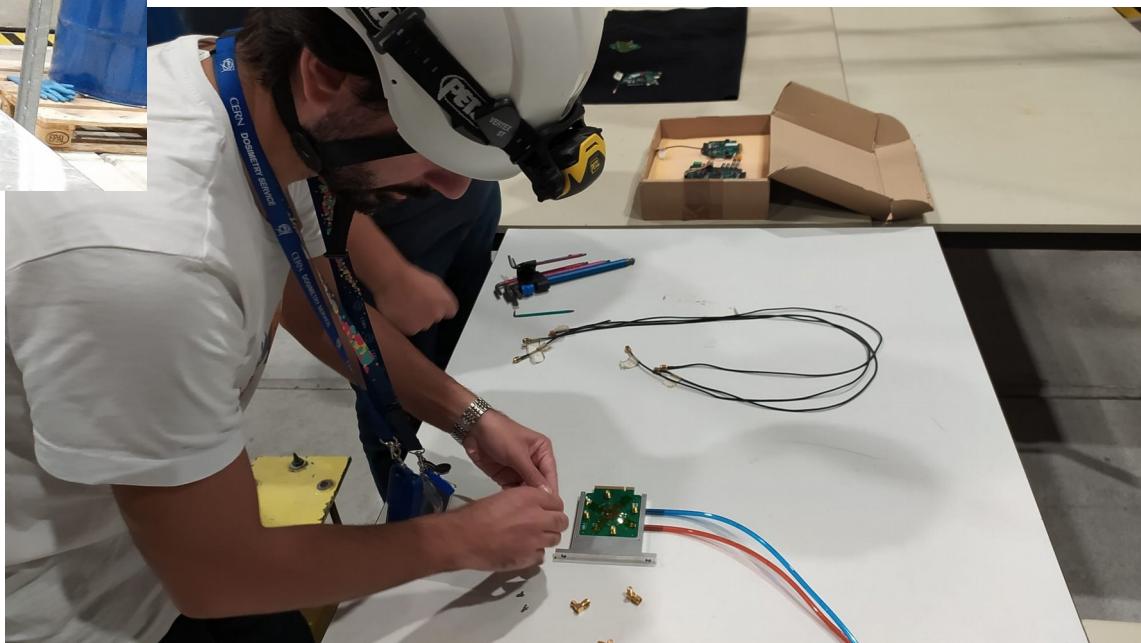


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Test Beam @ SPS (Sept-Oct 2024)



- “Our” sensor (i.e. APTS-OPAMP 65 nm AC coupled chip) during the test beam



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Test Beam @ SPS (Sept-Oct 2024): goal/timeline

- **Main goals**
 - Publication within June 2025
- **Milestones**
 - 31 October 2024 → Corryvrekan analysis until clusterization and time analysis until track association
 - 30 November 2024 → completing 55Fe measurements → updating all K_alpha database
 - 31 December 2020 → completing the Corryvrekan and time analysis
 - 31 January 2025 → first draft of the manuscript



Test Beam @ SPS (Sept-Oct 2024): goal/timeline



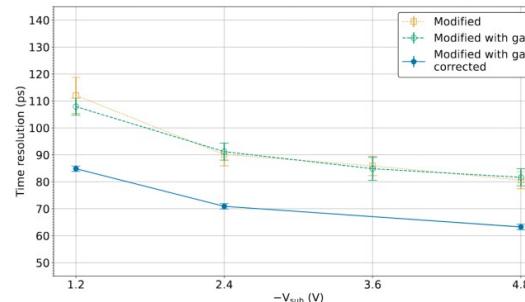
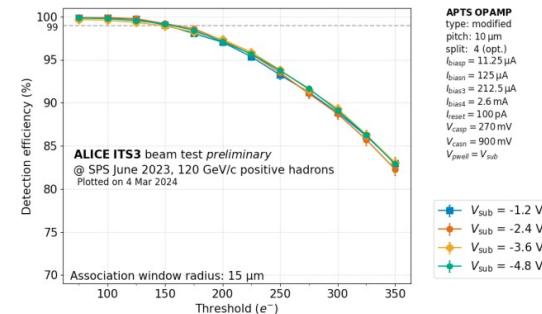
Roles

- **Sharing the analysis**

- Bari → AC-coupled chips -- W22AO10AP -- full analysis
- Nikhef → irradiated chips -- 1E14 and 1E15 -- full analysis
- Torino → complete support on analysis tools

- **Outcomes**

- efficiency at different clusterization thresholds
- timing trend for each configuration
- Landau trend for each configuration
- timing correction (for high statistics samples)
- timing in pixel (for high statistics samples)



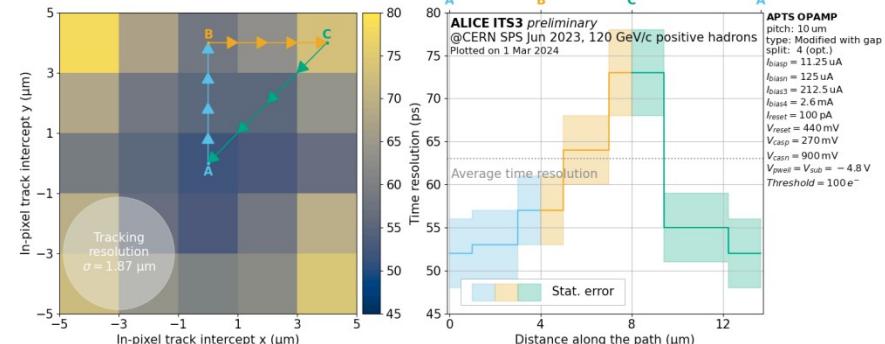
Test Beam @ SPS (Sept-Oct 2024): goal/timeline



Statistics

DUT	V _{sub} /HV (V)	Coincidences
W22AO10Pi1 (irradiated 1e14)	-4.8	37000
	-3.6	3000
	-2.4	3000
	-1.2	3000
W22AO10Pi1 (irradiated 1e15)	-4.8	34000
	-3.6	3000
	-2.4	3000
	-1.2	32000

DUT	V _{sub} /HV (V)	Coincidences
W22AO10APb44 (AC coupled)	4.8	10000
	7.2	11000
	10.8	17000
	14.4	11000
	18.0	3500



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Paper

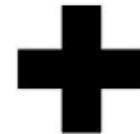
- **NIM A**

Time performance of Analog Pixel Test Structures with
in-chip operational amplifier implemented in 65 nm
CMOS imaging process

Gianluca Aglieri Rinella^h, Luca Aglietta^{a,b}, Matias Antonelli^g, Francesco Barile^{i,j}, Franco Benotto^b, Stefania Maria Beolè^{a,b}, Elena Botta^{a,b}, Giuseppe Eugenio Bruno^{k,j}, Francesca Carnesecchi^h, Domenico Colella^{i,j}, Angelo Colelli^{i,j}, Giacomo Contin^{f,g}, Giuseppe De Robertis^j, Florina Dumitrac^b, Domenico Elia^j, Chiara Ferrero^{c,b}, Martin Fransen^m, Alex Kluge^h, Shyam Kumar^j, Corentin Lemoine^{h,l}, Francesco Licciulli^j, Bong-Hwi Lim^{a,b}, Flavio Loddo^j, Magnus Mager^h, Davide Marras^{d,e}, Paolo Martinengo^h, Cosimo Pastore^j, Rajendra Nath Patra^{j,o}, Stefania Perciballi^{a,b}, Francesco Piro^h, Francesco Prino^b, Luciano Ramello^{b,n}, Arianna Grisel Torres Ramos^j, Felix Reidt^h, Roberto Russo^m, Valerio Saritzu^h, Umberto Savino^{a,b,*}, David Schledewitz^p, Mariia Selina^m, Serhiy Senyukov^l, Mario Sitta^{b,n}, Walter Snoeys^h, Jory Sonneveld^m, Miljenko Suljich^h, Triloki Triloki^{k,j}, Andrea Turcato^{a,b}

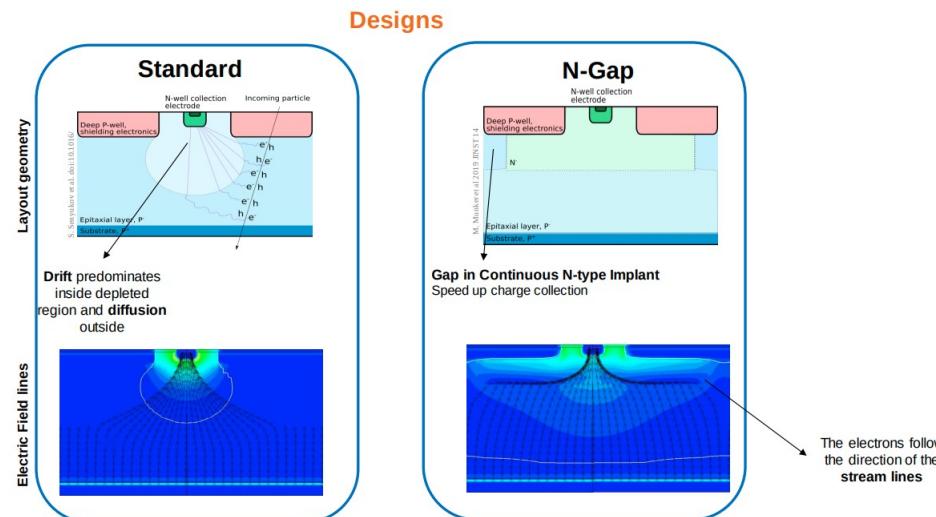
MC simulation: investigation E field

Technology Computer-Aided Design



Allpix Squared: a Monte Carlo simulation framework for semiconductor detectors

Electric field in thin silicon sensors



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New Fe-55 source (x2) - 37 MBq each

